

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX07F, TC74LCX07FN, TC74LCX07FT

Low-Voltage HEX Buffer with 5-V Tolerant Inputs and Outputs (open drain)

The TC74LCX07F/FN/FT is a high-performance CMOS buffer. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

The TC74LCX07 has high performance MOS N-channel transistor. (open-drain outputs)

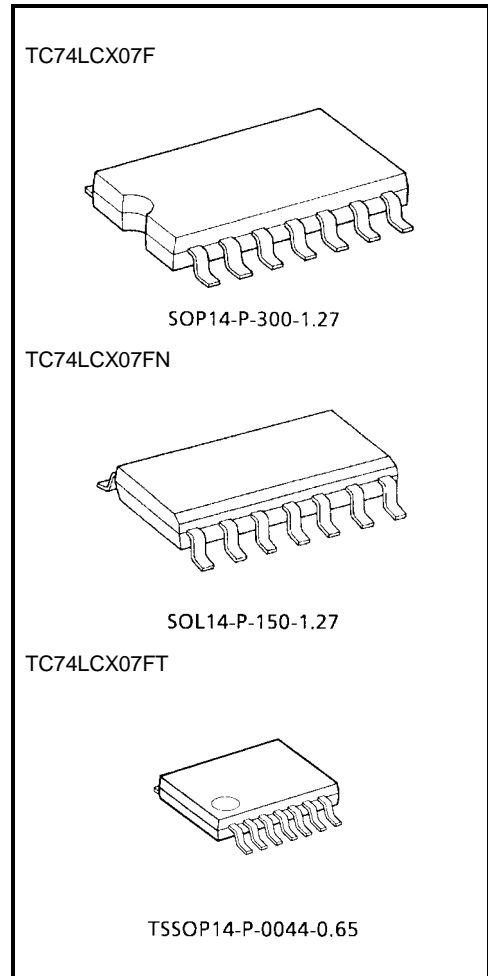
The device is designed for low-voltage (3.3 V) VCC applications, but it could be used to interface to 5-V supply environment for inputs.

All inputs are equipped with protection circuits against static discharge.

Features

- Low-voltage operation: $V_{CC} = 2.0$ to 3.6 V
- High-speed operation: $t_{pZ} = 3.7$ ns (max) ($V_{CC} = 3.0$ to 3.6 V)
- Output current: $I_{OL} = 24$ mA (min) ($V_{CC} = 3.0$ V)
- Latch-up performance: -500 mA
- Available in JEDEC SOP, JEITA SOP and TSSOP
- Open-drain outputs
- Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 07 type

Note: xxxFN (JEDEC SOP) is not available in Japan.



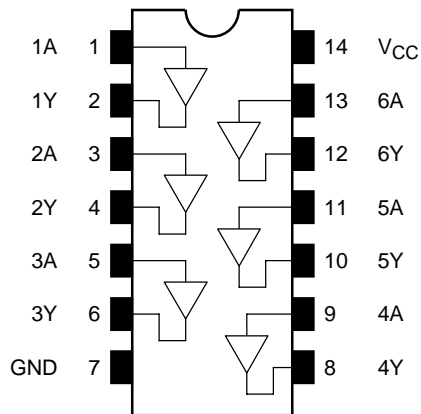
Weight

SOP14-P-300-1.27: 0.18 g (typ.)

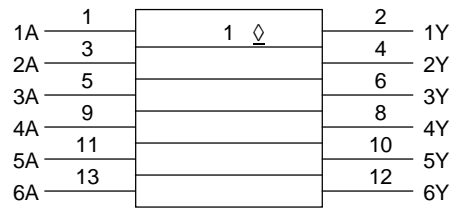
SOP14-P-150-1.27: 0.12 g (typ.)

TSSOP14-P-0044-0.65: 0.06 g (typ.)

Pin Assignment (top view)



IEC Logic Symbol

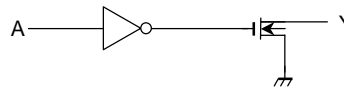


Truth Table

Inputs	Outputs
A	Y
L	L
H	Z

Z: High impedance

System Diagram (per gate)



Maximum Ratings

Characteristics	Symbol	Rating	Unit
Power supply voltage	V_{CC}	-0.5 to 7.0	V
DC input voltage	V_{IN}	-0.5 to 7.0	V
DC output voltage	V_{OUT}	-0.5 to 7.0 (Note 1)	V
		-0.5 to $V_{CC} + 0.5$ (Note 2)	
Input diode current	I_{IK}	-50	mA
Output diode current	I_{OK}	-50 (Note 3)	mA
DC output current	I_{OUT}	50	mA
Power dissipation	P_D	180	mW
DC V_{CC} /ground current	I_{CC}/I_{GND}	± 100	mA
Storage temperature	T_{stg}	-65 to 150	$^{\circ}C$

Note 1: Output in OFF state

Note 2: Low state. I_{OUT} absolute maximum rating must be observed.

Note 3: $V_{OUT} < GND$

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Power supply voltage	V_{CC}	2.0 to 3.6	V
		1.5 to 3.6 (Note 4)	
Input voltage	V_{IN}	0 to 5.5	V
Output voltage	V_{OUT}	0 to 5.5 (Note 5)	V
		0 to V_{CC} (Note 6)	
Output current	I_{OL}	24 (Note 7)	mA
		12 (Note 8)	
Operating temperature	T_{opr}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 10 (Note 9)	ns/V

Note 4: Data retention only

Note 5: Output in OFF state

Note 6: Low state

Note 7: $V_{CC} = 3.0$ to 3.6 V

Note 8: $V_{CC} = 2.7$ to 3.0 V

Note 9: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V

Electrical Characteristics

DC Characteristics ($T_a = -40$ to 85°C)

Characteristics		Symbol	Test Condition	V_{CC} (V)	Min	Max	Unit	
Input voltage	H-level	V_{IH}	—	2.7 to 3.6	2.0	—	V	
	L-level	V_{IL}	—	2.7 to 3.6	—	0.8		
Output voltage	L-level	V_{OL}	$V_{IN} = V_{IL}$	$I_{OL} = 100 \mu\text{A}$	2.7 to 3.6	—	0.2	V
				$I_{OL} = 12 \text{ mA}$	2.7	—	0.4	
				$I_{OL} = 16 \text{ mA}$	3.0	—	0.4	
				$I_{OL} = 24 \text{ mA}$	3.0	—	0.55	
Input leakage current		I_{IN}	$V_{IN} = 0$ to 5.5 V	2.7 to 3.6	—	± 5.0	μA	
Output OFF state current		I_{OZ}	$V_{IN} = V_{IH}$, $V_{OUT} = 0$ to 5.5 V	2.7 to 3.6	—	± 5.0	μA	
Power-off leakage current		I_{OFF}	$V_{IN}/V_{OUT} = 5.5$ V	0	—	10.0	μA	
Quiescent supply current		I_{CC}	$V_{IN} = V_{CC}$ or GND	2.7 to 3.6	—	10.0	μA	
			$V_{IN}/V_{OUT} = 3.6$ to 5.5 V	2.7 to 3.6	—	± 10.0		
Increase in I_{CC} per input		ΔI_{CC}	$V_{IH} = V_{CC} - 0.6$	2.7 to 3.6	—	500		

AC Characteristics (Ta = -40 to 85°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Output enable time	t _{pZL}	Figure 1, Figure 2	2.7	1.0	4.4	ns
			3.3 ± 0.3	0.8	3.7	
Output disable time	t _{pLZ}	Figure 1, Figure 2	2.7	1.0	4.4	ns
			3.3 ± 0.3	0.8	3.7	
Output to output skew	t _{osZL}	(Note 10)	2.7	—	—	ns
			3.3 ± 0.3	—	1.0	

Note 10: Parameter guaranteed by design.
 (t_{osZL} = |t_{pZLm} - t_{pZLn}|)

Dynamic Switching Characteristics (Ta = 25°C, input: t_r = t_f = 2.5 ns, C_L = 50 pF, R_L = 500 Ω)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Typ.	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	V _{IH} = 3.3 V, V _{IL} = 0 V	3.3	0.8	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	V _{IH} = 3.3 V, V _{IL} = 0 V	3.3	0.8	V

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Typ.	Unit
Input capacitance	C _{IN}	—	3.3	7	pF
Output capacitance	C _{OUT}		3.3	8	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz (Note 11)	3.3	5	pF

Note 11: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6 \text{ (per gate)}$$

AC Test Circuit

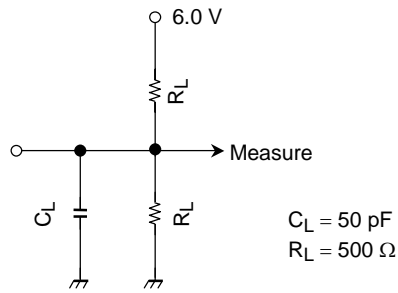


Figure 1

AC Waveform

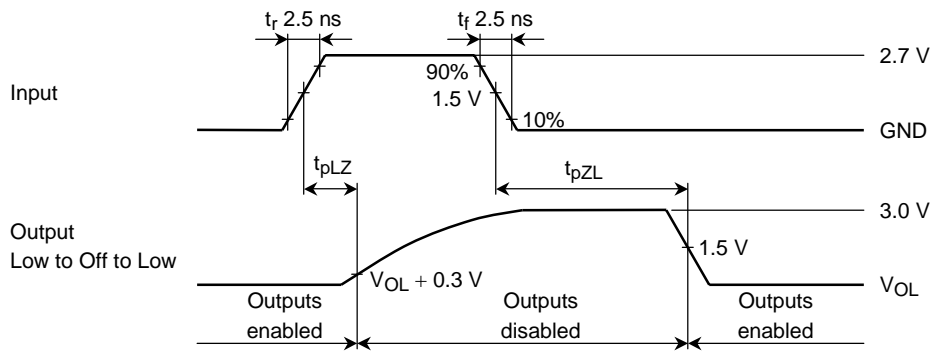
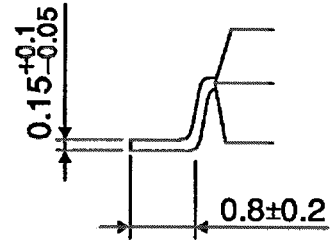
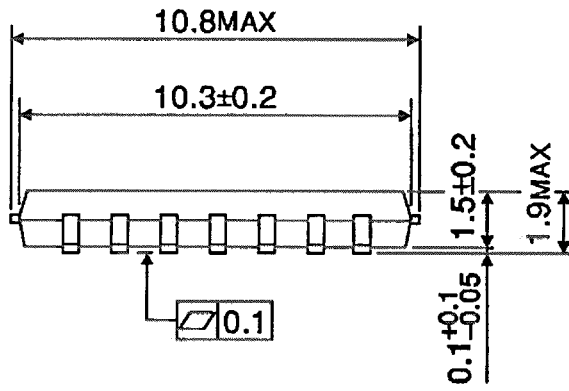
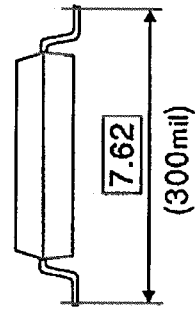
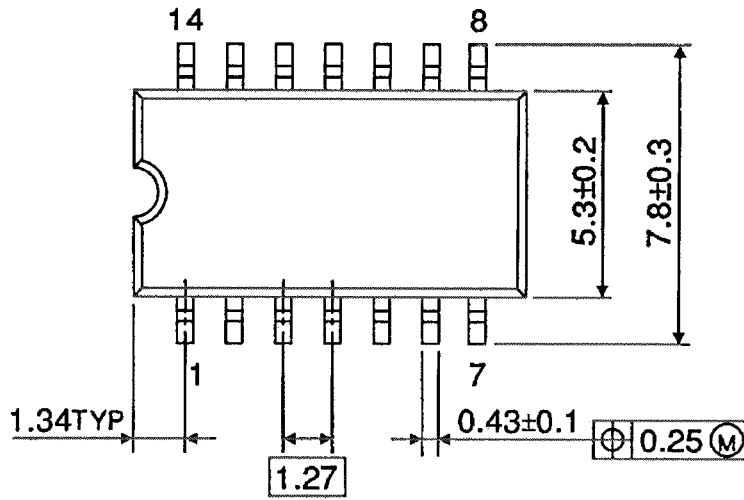


Figure 2 t_{pLZ} , t_{pZL}

Package Dimensions

SOP14-P-300-1.27

Unit : mm



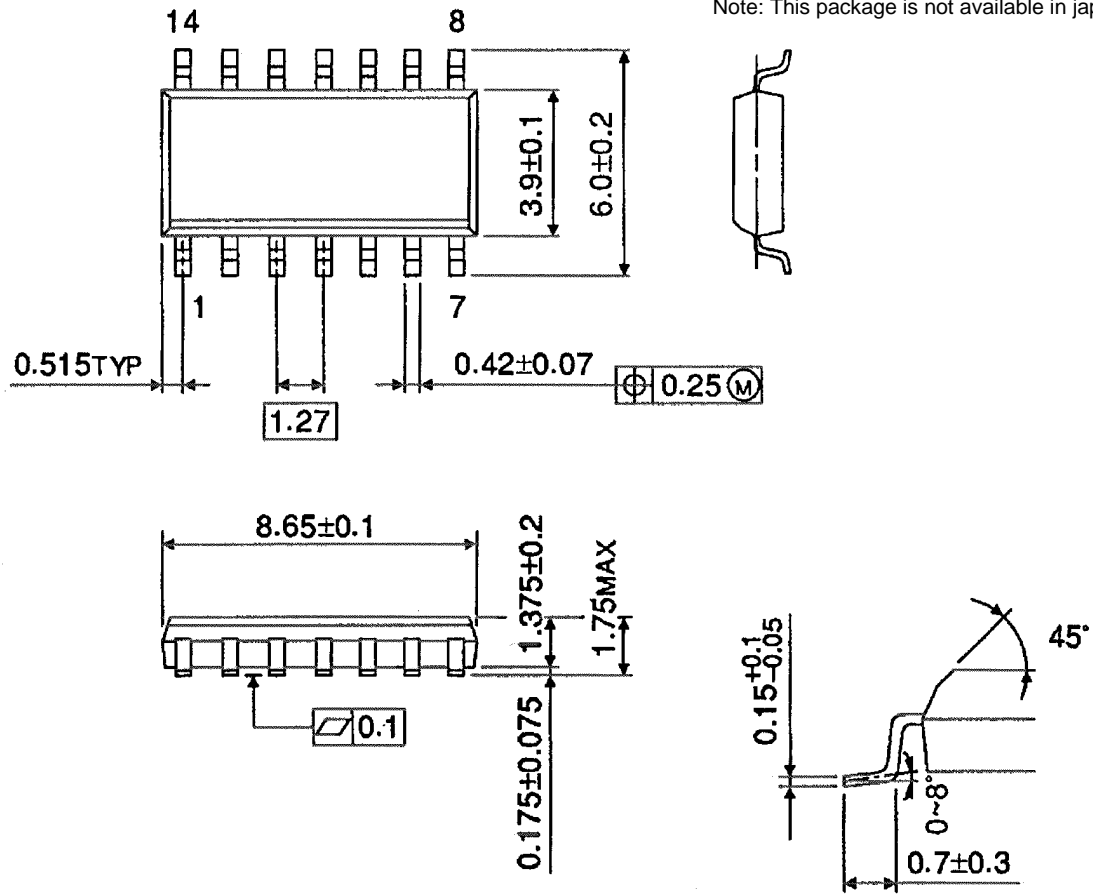
Weight: 0.18 g (typ.)

Package Dimensions

SOL14-P-150-1.27

Unit : mm

Note: This package is not available in japan.

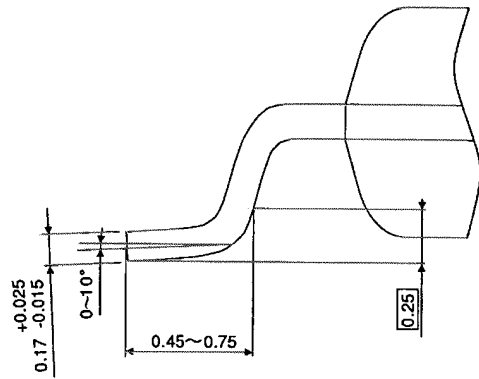
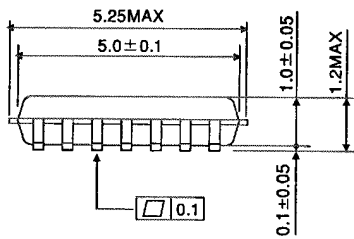
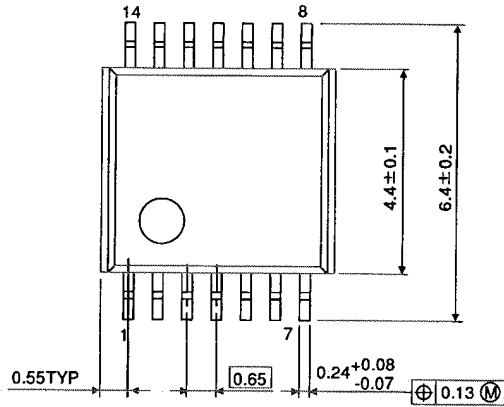


Weight: 0.12 g (typ.)

Package Dimensions

TSSOP14-P-0044-0.65

Unit : mm



Weight: 0.06 g (typ.)

RESTRICTIONS ON PRODUCT USE

000707EBA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.